

## 60V/3A N-Channel MOSFET

### Features

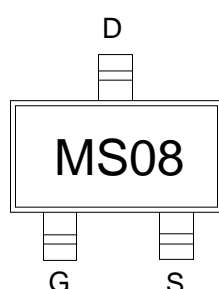
- Excellent package for good heat dissipation
- Ultra low gate charge
- Low reverse transfer capacitance
- Fast switching capability
- Avalanche energy specified

### Application

- Power switching application

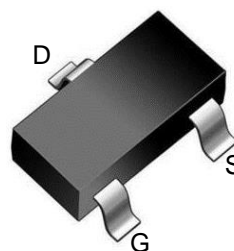
### Product Summary

|          |                  |           |
|----------|------------------|-----------|
| $V_{DS}$ | $R_{DS(ON)}$ MAX | $I_D$ MAX |
| 60V      | 100mΩ@10V        | 3A        |
|          | 150mΩ@4.5V       |           |

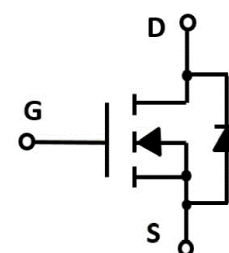


MS08: Device code

Marking and pin assignment



SOT-23 top view



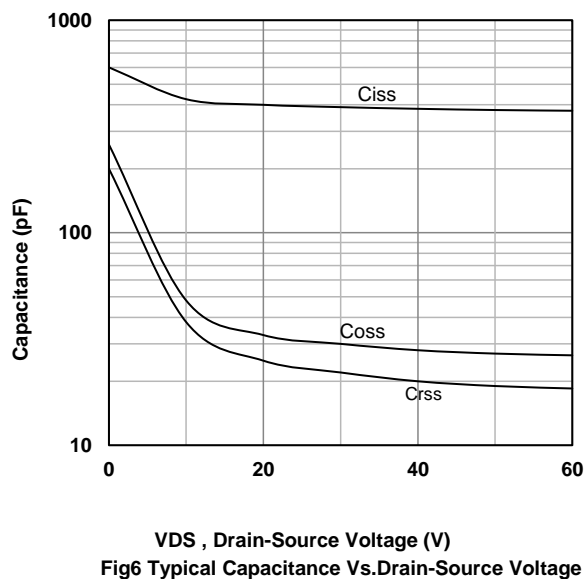
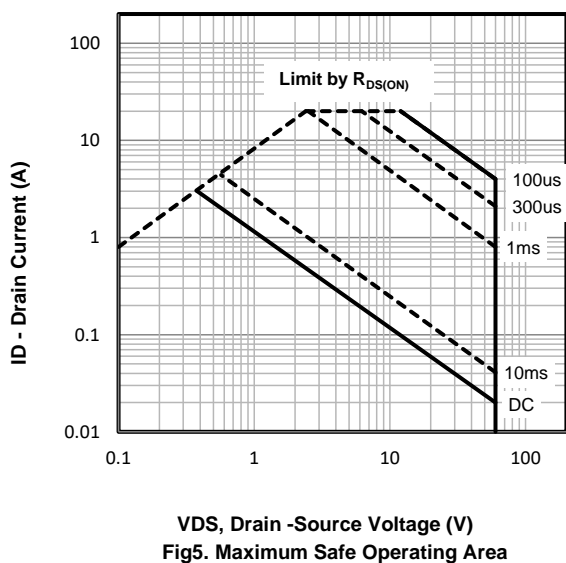
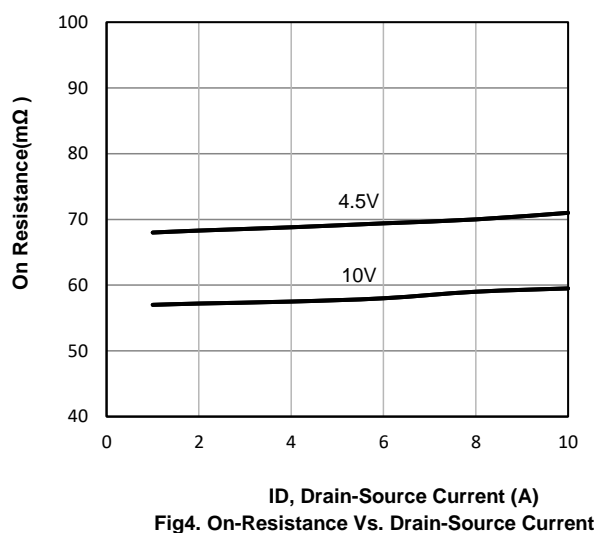
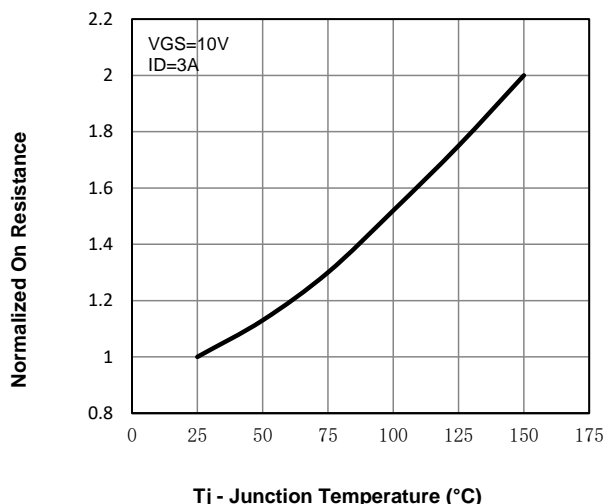
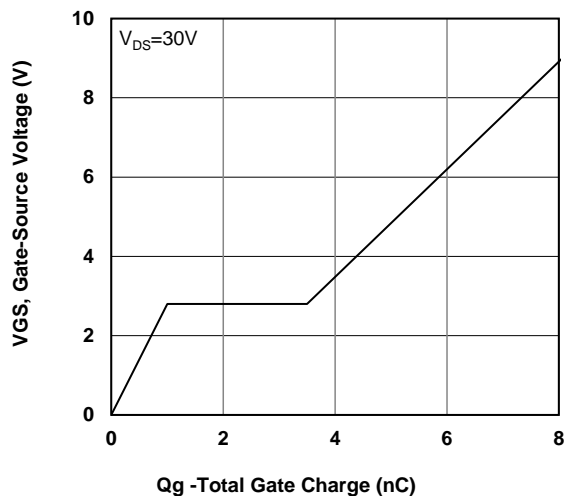
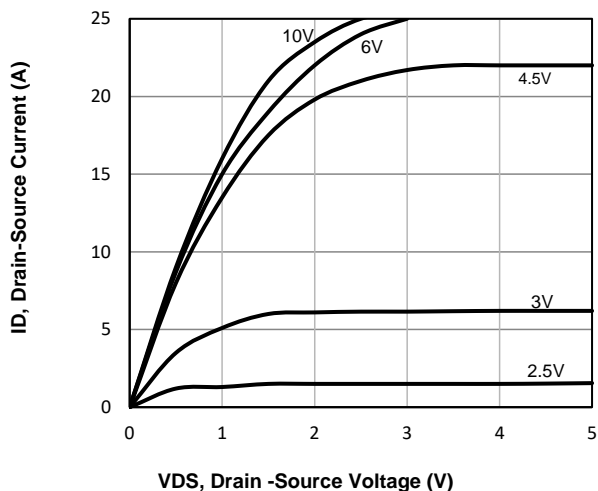
Schematic diagram

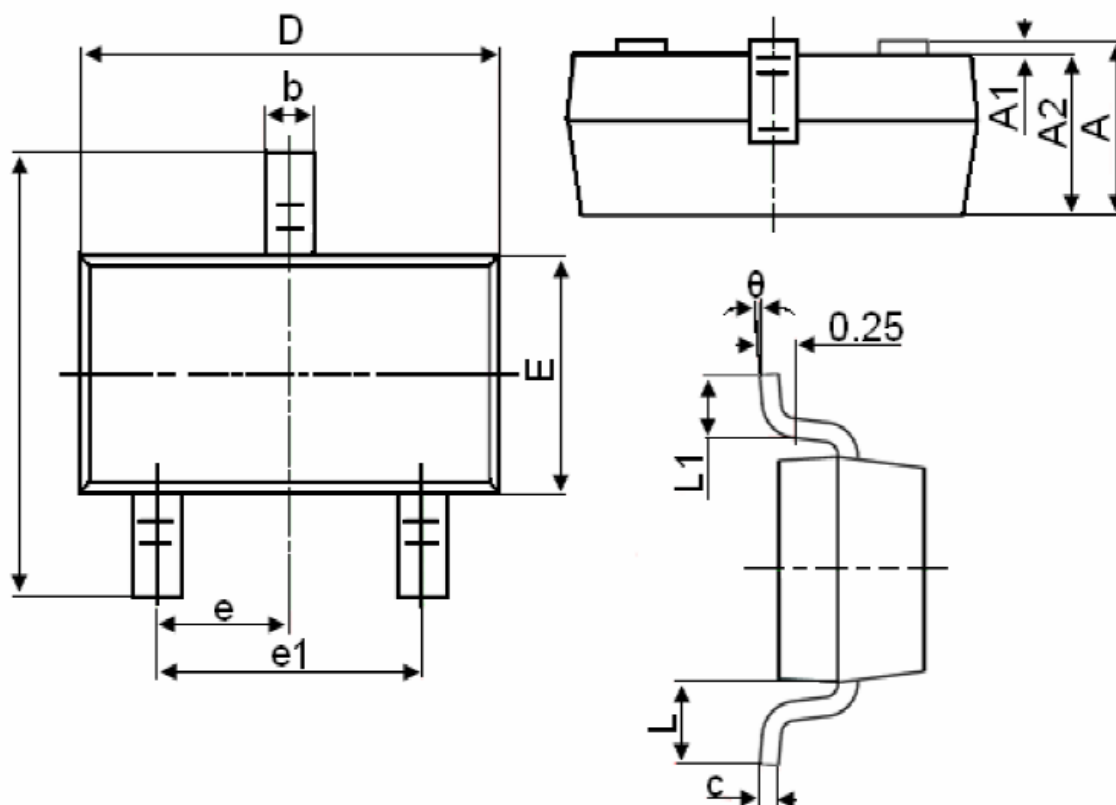


| Absolute Maximum Ratings (TA=25°C unless otherwise noted) |  |                        |            |      |
|---|--|------------------------|------------|------|
| Symbol  | Parameter  |                        | Rating     | Unit |
| <b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>    |  |                        |            |      |
| $V_{DS}$  | Drain-Source Breakdown Voltage   |                        | 60         | V    |
| $V_{GS}$  | Gate-Source Voltage  |                        | ±20        | V    |
| $T_J$   | Maximum Junction Temperature   |                        | 150        | °C   |
| $T_{STG}$   | Storage Temperature Range  |                        | -55 to 150 | °C   |
| $I_S$   | Diode Continuous Forward Current                                       | $T_C=25^\circ\text{C}$ | 3          | A    |
| <b>Mounted on Large Heat Sink</b>                         |  |                        |            |      |
| $I_{DM}$  | Pulse Drain Current Tested   | $T_C=25^\circ\text{C}$ | 12         | A    |
| $I_D$   | Continuous Drain Current@GS=10V  | $T_C=25^\circ\text{C}$ | 3          | A    |
| $P_D$   | Maximum Power Dissipation  | $T_C=25^\circ\text{C}$ | 0.35       | W    |
| $R_{\theta JA}$   | Thermal Resistance Junction-Ambient>(*1 in2 Pad of 2-oz Copper), Max.) |                        | 375        | °C/W |

| <b>Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)</b>              |                                  |   |            |            |            |             |
|--|----------------------------------|---|------------|------------|------------|-------------|
| <b>Symbol</b>  | <b>Parameter</b>                 | <b>Condition</b>                          | <b>Min</b> | <b>Typ</b> | <b>Max</b> | <b>Unit</b> |
| <b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>  |                                  |   |            |            |            |             |
| BV <sub>(BR)DSS</sub>  | Drain-Source Breakdown Voltage   | VGS=0V, ID=250μA                          | 60         | --         | --         | V           |
| I <sub>DSS</sub>   | Zero Gate Voltage Drain Current  | VDS=60V, VGS=0V                           | --         | --         | 1          | μA          |
| I <sub>GSS</sub>   | Gate-Body Leakage Current        | VGS=±20V, VDS=0V                          | --         | --         | ±100       | nA          |
| V <sub>GS(th)</sub>  | Gate Threshold Voltage           | VDS=VGS, ID=250μA                         | 1.1        | 1.7        | 2.5        | V           |
| R <sub>DS(on)</sub>  | Drain-Source On-State Resistance | VGS=10V, ID=3A                            | --         | 58         | 100        | mΩ          |
|  |                                  | VGS=4.5V, ID=2A                           | --         | 70         | 150        |             |
| <b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b> |                                  |   |            |            |            |             |
| C <sub>ISS</sub>   | Input Capacitance                | VDS=30V, VGS=0V,<br>f=1MHz                | --         | 400        | --         | pF          |
| C <sub>OSS</sub>   | Output Capacitance               |   | --         | 28         | --         | pF          |
| C <sub>RSS</sub>   | Reverse Transfer Capacitance     |   | --         | 23         | --         | pF          |
| <b>Switching Characteristics</b>   |                                  |   |            |            |            |             |
| Q <sub>g</sub>   | Total Gate Charge                | VDS=30V, ID=3A,<br>VGS=10V                | --         | 9          | --         | nC          |
| Q <sub>gs</sub>  | Gate Source Charge               |   | --         | 1          | --         | nC          |
| Q <sub>gd</sub>  | Gate Drain Charge                |   | --         | 2.5        | --         | nC          |
| t <sub>d(on)</sub>   | Turn-on Delay Time               | VDD=30V, ID=3A,<br>VGS=10V, RG=2.3Ω       | --         | 4          | --         | nS          |
| t <sub>r</sub>   | Turn-on Rise Time                |   | --         | 10         | --         | nS          |
| t <sub>d(off)</sub>  | Turn-Off Delay Time              |   | --         | 12.5       | --         | nS          |
| t <sub>f</sub>   | Turn-Off Fall Time               |   | --         | 1.8        | --         | nS          |
| <b>Source- Drain Diode Characteristics</b>   |                                  |   |            |            |            |             |
| V <sub>SD</sub>  | Forward on voltage               | T <sub>J</sub> =25°C, I <sub>s</sub> =3A, | --         | 0.8        | 1.2        | V           |

## Typical Operating Characteristics



**SOT-23 Package information**


| Symbol   | Dimensions in Millimeters(mm) |       | Dimensions In Inches |       |
|----------|-------------------------------|-------|----------------------|-------|
|          | Min                           | Max   | Min                  | Max   |
| A        | 0.900                         | 1.150 | 0.035                | 0.045 |
| A1       | 0.000                         | 0.100 | 0.000                | 0.004 |
| A2       | 0.900                         | 1.050 | 0.035                | 0.041 |
| b        | 0.300                         | 0.500 | 0.012                | 0.020 |
| c        | 0.080                         | 0.150 | 0.003                | 0.006 |
| D        | 2.800                         | 3.000 | 0.110                | 0.118 |
| E        | 1.200                         | 1.400 | 0.047                | 0.055 |
| E1       | 2.250                         | 2.550 | 0.089                | 0.100 |
| e        | 0.950TYP                      |       | 0.037TYP             |       |
| e1       | 1.800                         | 2.000 | 0.071                | 0.079 |
| L        | 0.550REF                      |       | 0.022REF             |       |
| L1       | 0.300                         | 0.500 | 0.012                | 0.020 |
| $\theta$ | 0°                            | 8°    | 0°                   | 8°    |